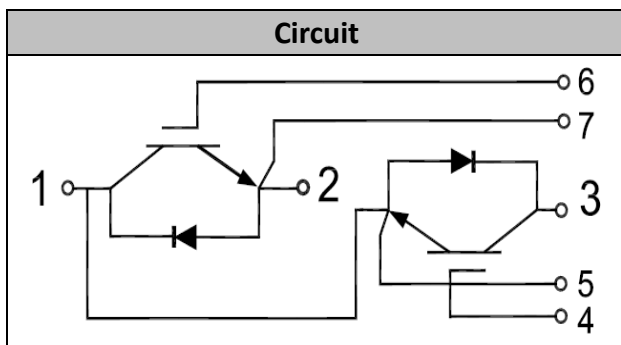


## IGBT Modules

V <sub>CES</sub>	1200V
I <sub>C</sub>	300A

## Applications

- High frequency drivers
- Solar inverters
- UPS (Uninterruptible Power Supplies)
- Electric welding machine



## Features

- High speed IGBT in NPT technology
- Low switching losses
- High short circuit capability(10us)
- Including ultra fast & soft recovery anti-parallel FWD
- Low inductance
- Maximum junction temperature 150°C

## ● IGBT

### Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
Collector-Emitter Voltage	V <sub>CES</sub>	V <sub>GE</sub> =0V, I <sub>C</sub> =1mA, T <sub>vj</sub> =25°C	1200	V
Continuous Collector Current	I <sub>C</sub>	T <sub>c</sub> =80°C	300	A
Repetitive Peak Collector Current	I <sub>CRM</sub>	tp=1ms	600	A
Gate-Emitter Voltage	V <sub>GES</sub>	T <sub>vj</sub> =25°C	±20	V
Total Power Dissipation	P <sub>tot</sub>	T <sub>c</sub> =25°C T <sub>vjmax</sub> =150°C	2000	W

**Characteristic values**

Parameter	Symbol	Conditions	Value			Unit	
			Min.	Typ.	Max.		
Gate-emitter Threshold Voltage	$V_{GE(th)}$	$V_{GE}=V_{CE}, I_C=12mA, T_{vj}=25^{\circ}C$	5.0	5.8	6.5	V	
Collector-Emitter Cut-off Current	$I_{CES}$	$V_{CE}=1200V, V_{GE}=0V, T_{vj}=25^{\circ}C$			1.0	mA	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=300A, V_{GE}=15V, T_{vj}=25^{\circ}C$		3.0	3.5	V	
		$I_C=300A, V_{GE}=15V, T_{vj}=125^{\circ}C$		3.8			
Gate Charge	$Q_G$			3.4		uC	
Input Capacitance	$C_{ies}$	$V_{CE}=25V, V_{GE}=0V,$ $f=1MHz, T_{vj}=25^{\circ}C$		19.3		nF	
Reverse Transfer Capacitance	$C_{res}$				1.2		nF
Gate-Emitter leakage current	$I_{GES}$	$V_{CE}=0V, V_{GE}=20V, T_{vj}=25^{\circ}C$			400	nA	
Turn-on Delay Time	$t_{d(on)}$	$I_C=300A$ $V_{CE}=600V$ $V_{GE}=\pm 15V$ $R_{GON}=3.3\Omega$ $R_{GOFF}=1.7\Omega$ $T_{vj}=25^{\circ}C$		105		ns	
Rise Time	$t_r$				80		ns
Turn-off Delay Time	$t_{d(off)}$				288		ns
Fall Time	$t_f$				25		ns
Energy Dissipation During Turn-on Time	$E_{on}$				33.5		mJ
Energy Dissipation During Turn-off Time	$E_{off}$				8.3		mJ
Turn-on Delay Time	$t_{d(on)}$	$I_C=300A$ $V_{CE}=600V$ $V_{GE}=\pm 15V$ $R_{GON}=3.3\Omega$ $R_{GOFF}=1.7\Omega$ $T_{vj}=125^{\circ}C$		114		ns	
Rise Time	$t_r$				87		ns
Turn-off Delay Time	$t_{d(off)}$				332		ns
Fall Time	$t_f$				29		ns
Energy Dissipation During Turn-on Time	$E_{on}$				46.7		mJ
Energy Dissipation During Turn-off Time	$E_{off}$				11.8		mJ
SC Data	$I_{sc}$	$T_p \leq 10\mu s, V_{GE}=15V,$ $T_{vj}=150^{\circ}C, V_{cc}=600V,$ $V_{CEM} \leq 1200V$		2200		A	



## ● Diode

### Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	$T_{vj}=25^{\circ}C$	1200	V
Continuous DC Forward Current	$I_F$		300	A
Repetitive Peak Forward Current	$I_{FRM}$	$t_p=1ms$	600	A

### Characteristic values

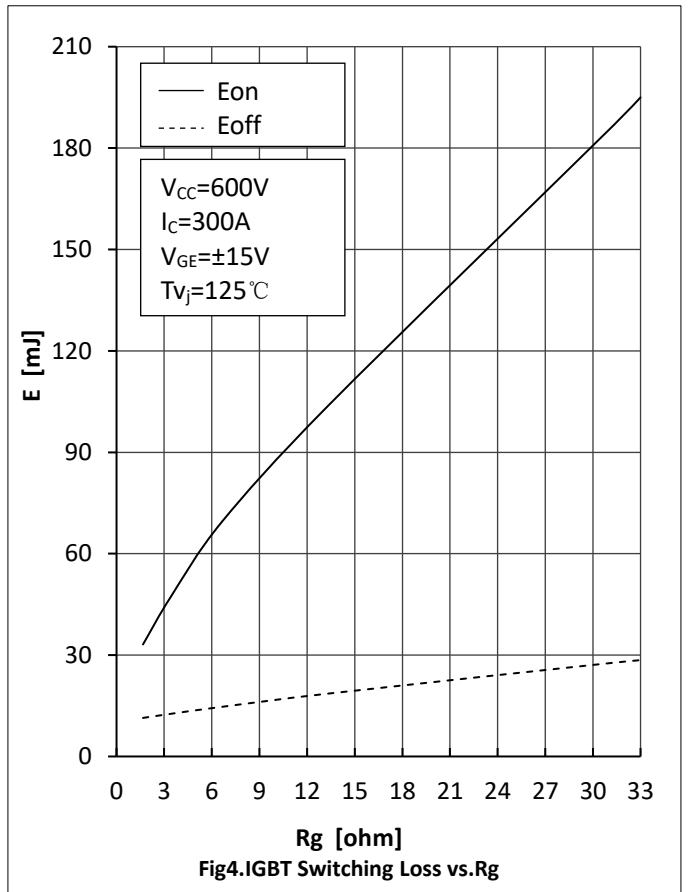
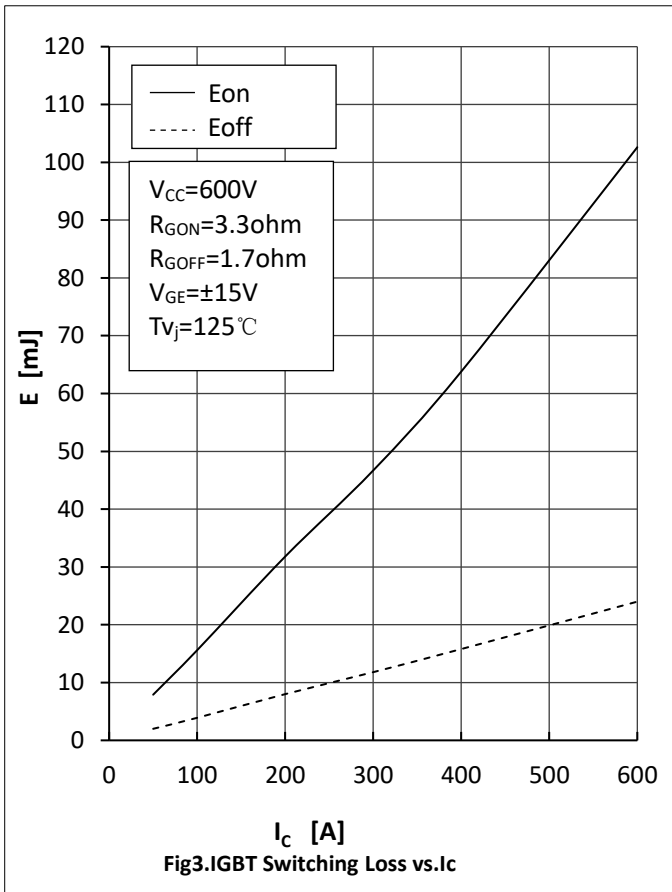
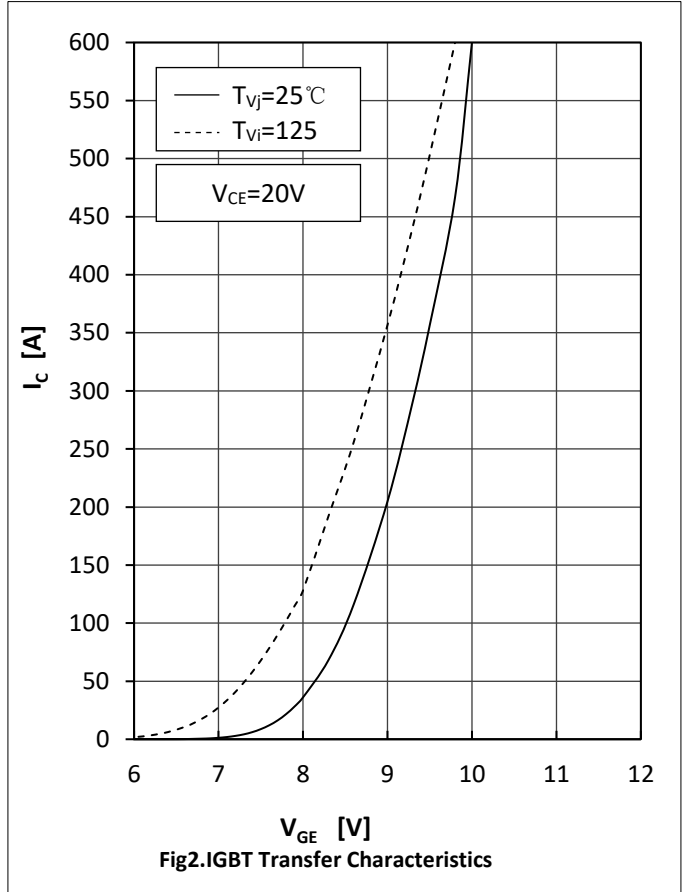
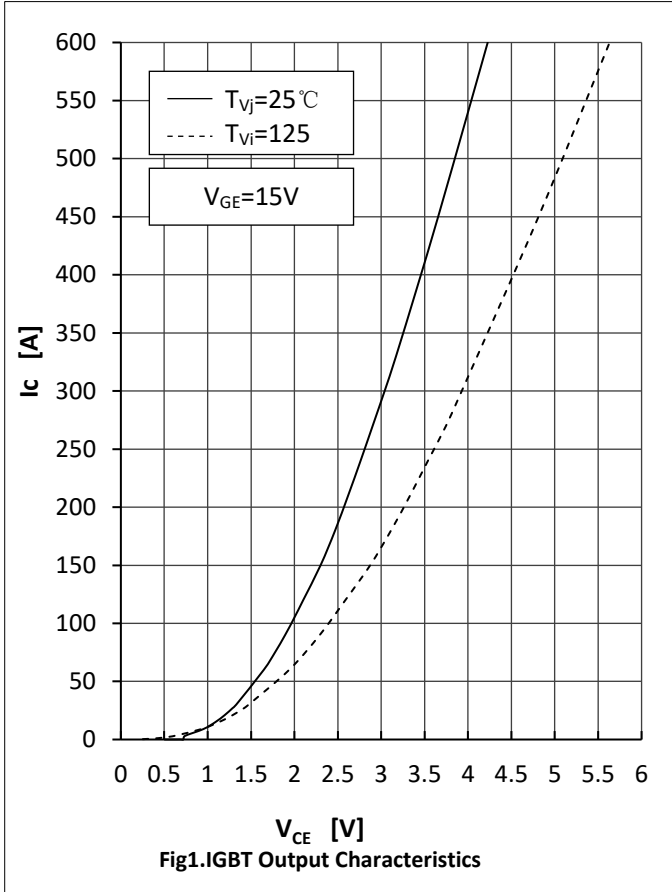
Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Forward Voltage	$V_F$	$I_F=300A, T_{vj}=25^{\circ}C$		1.70	2.0	V
		$I_F=300A, T_{vj}=125^{\circ}C$		1.75		
Recovered Charge	$Q_{rr}$	$I_F=300A$		16.8		$\mu C$
Peak Reverse Recovery Current	$I_{rr}$	$V_R=600V$ $-di_F/dt=3600A/\mu s$		240		A
Reverse Recovery Energy	$E_{rec}$	$T_{vj}=25^{\circ}C$		10.2		mJ
Recovered Charge	$Q_{rr}$	$I_F=300A$		36.5		$\mu C$
Peak Reverse Recovery Current	$I_{rr}$	$V_R=600V$ $-di_F/dt=3600A/\mu s$		290		A
Reverse Recovery Energy	$E_{rec}$	$T_{vj}=125^{\circ}C$		20.3		mJ

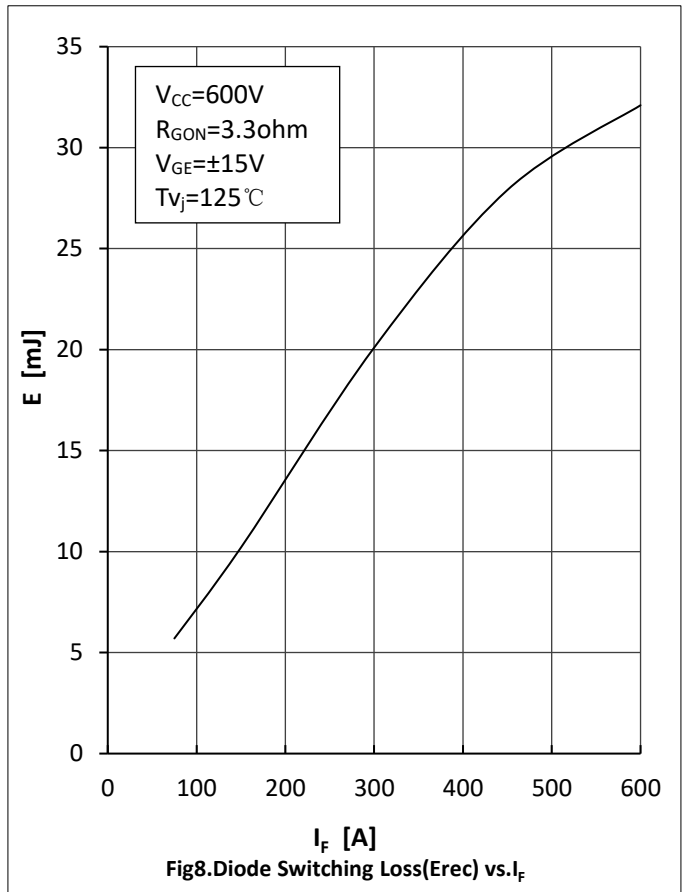
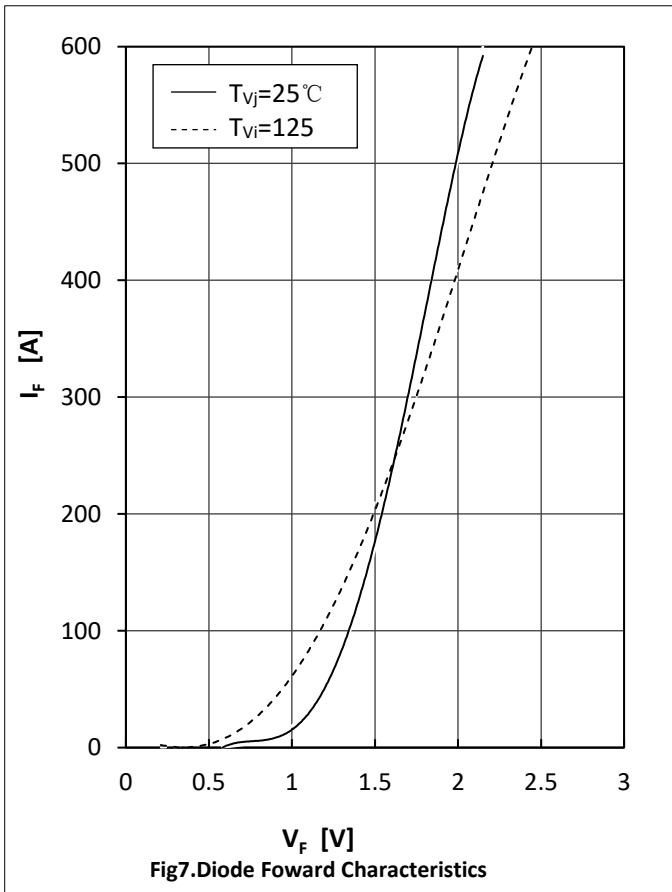
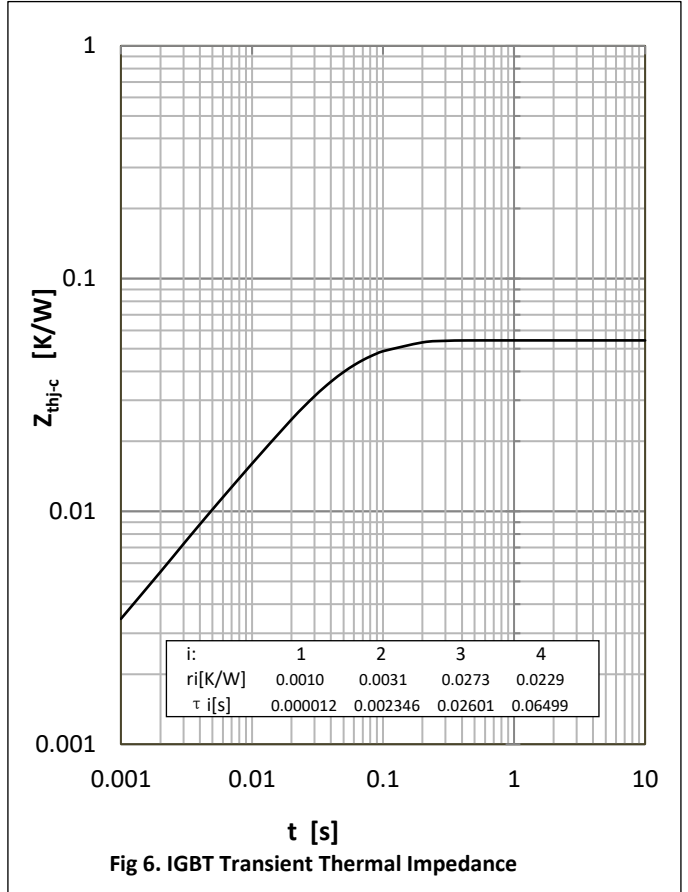
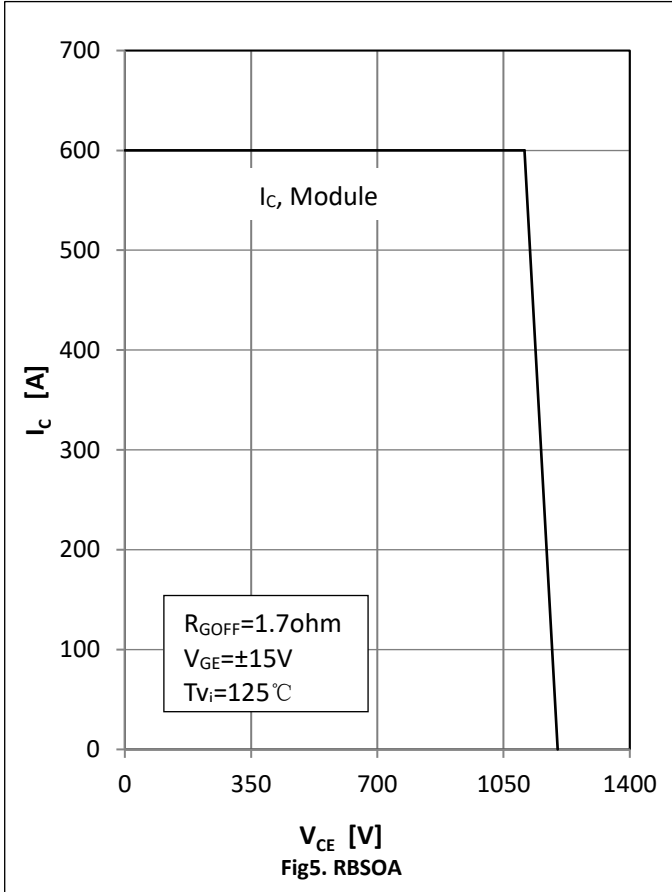


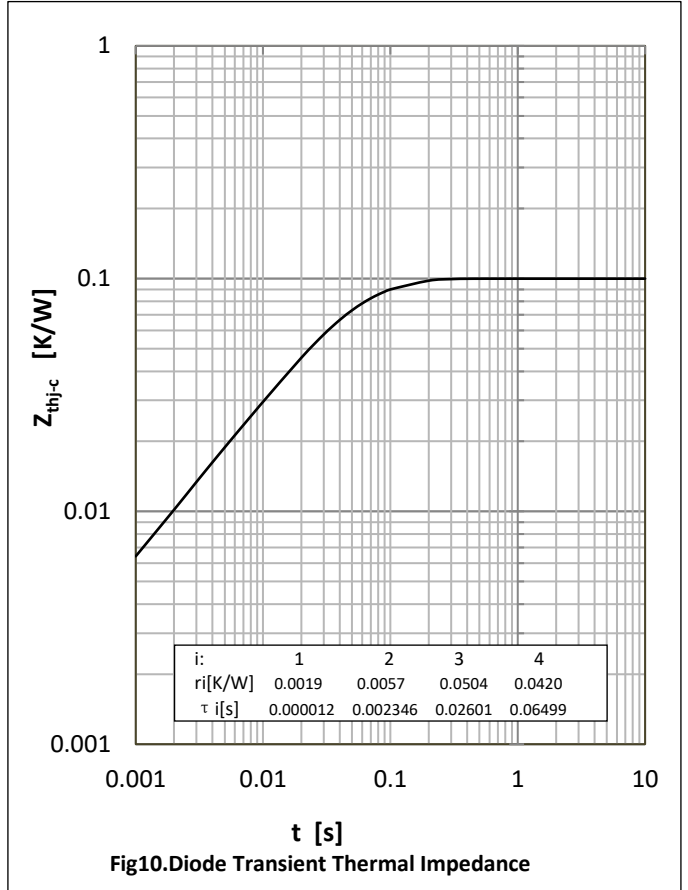
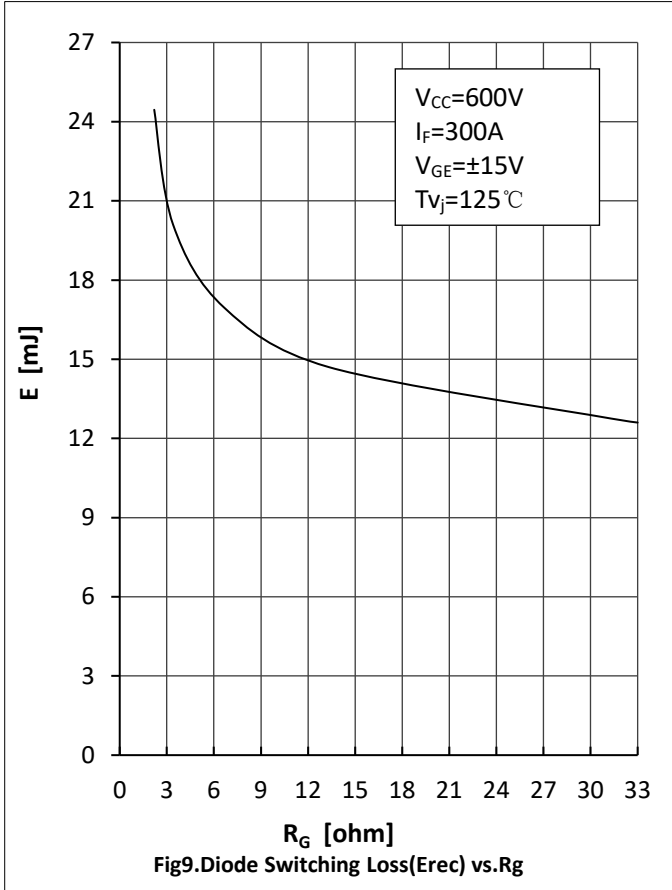
## ● Module Characteristics

$T_c=25^{\circ}\text{C}$  unless otherwise specified

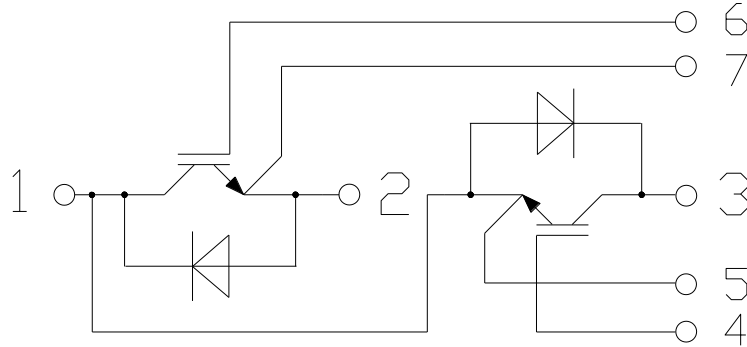
Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Isolation voltage	$V_{\text{isol}}$	$t=1\text{min}, f=50\text{Hz}$	2500			V
Maximum Junction Temperature	$T_{\text{jmax}}$				150	$^{\circ}\text{C}$
Operating Junction Temperature	$T_{\text{vjop}}$		-40		125	$^{\circ}\text{C}$
Storage Temperature	$T_{\text{stg}}$		-40		125	$^{\circ}\text{C}$
Thermal Resistance Junction-to Case	$R_{\theta\text{JC}}$	per IGBT			0.06	K/W
		per Diode			0.10	
Thermal Resistance Case-to Sink	$R_{\theta\text{CS}}$	Conductive grease applied		0.035		K/W
Module Electrodes Torque	$M_t$	Recommended(M6)	3.0		5.0	N·m
Module-to-Sink Torque	$M_s$	Recommended(M6)	3.0		5.0	N·m
Weight of Module	G			315		g







● **Circuit Diagram**



● **Package Outline Information**

Dimensions in Millimeters

